### **Vishay Semiconductors**

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# Hyperfast Rectifier, 15 A FRED Pt®



DPAK (TO-252AA)

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	15 A							
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.5 V							
t <sub>rr</sub> (typ.)	18 ns							
T <sub>J</sub> max.	175 °C							
Package	DPAK (TO-252AA)							
Circuit configuration	Single							

#### FEATURES

- Hyperfast recovery time, extremely low Q<sub>rr</sub>
- 175 °C maximum operating junction temperature
- For PFC CCM operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum FREE peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 117 °C	15							
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$	120	А						
Peak repetitive forward current	I <sub>FM</sub>	$T_{C} = 117 \text{ °C}, f = 20 \text{ kHz}, d = 50 \%$	30							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-				
Forward voltage		I <sub>F</sub> = 15 A - 2.3				v			
	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C	-	1.6	1.9				
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.5	1.8	]			
		$V_{R} = V_{R}$ rated	-	-	50				
Reverse leakage current	I <sub>R</sub>	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	200	μA			
		$T_J = 150 \ ^{\circ}C, \ V_R = V_R \ rated$	-	-	300				
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	11	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH			

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 1
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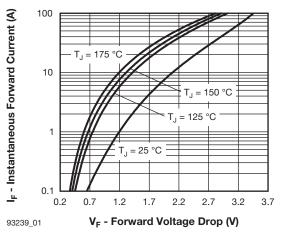
**ROHS** COMPLIANT

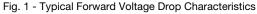


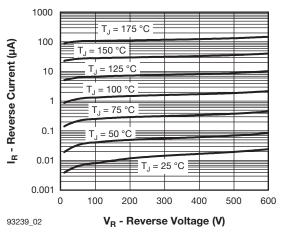
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	18	22				
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	-	22	-					
	t <sub>rr</sub>	$I_{\rm F} = 15 \text{ A},  dI_{\rm F}/dt = 7$	-	17	32	ns				
		T <sub>J</sub> = 25 °C		-	22	-				
		T <sub>J</sub> = 125 °C		-	38	-				
Pool room ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_{\rm F} = 15  {\rm A}$	-	3.1	-	А			
Peak recovery current		T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 200 A/µs V <sub>R</sub> = 390 V	-	4.6	-	A			
Deverse receiver allower	0	T <sub>J</sub> = 25 °C		-	37	-	nC			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	92	-				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C			
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	1.4	1.8	°C/W			
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	70	0/10			
Approvimate weight			0.3			g			
Approximate weight				0.01		oz.			
Marking device		Case style DPAK (TO-252AA)	15EWX06FN						









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## VS-15EWX06FN-M3

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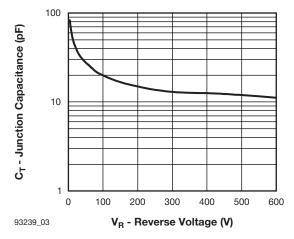


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

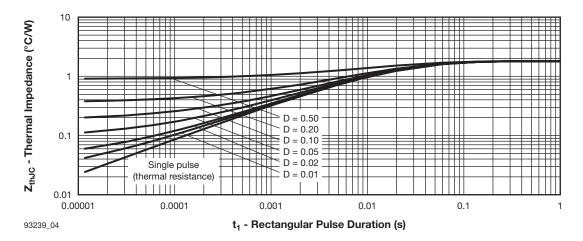
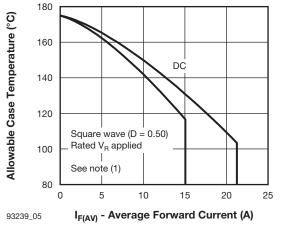
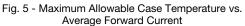


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





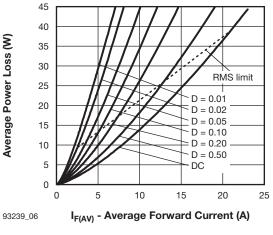


Fig. 6 - Forward Power Loss Characteristics

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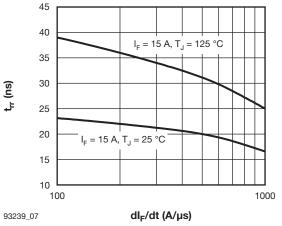


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt



- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd<sub>REV</sub> = inverse power loss =  $V_{R1} \times I_R$  (1 D);  $I_R$  at  $V_{R1}$  = rated  $V_R$

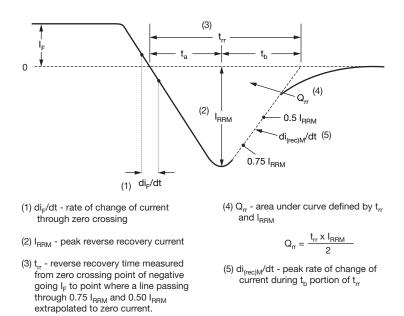
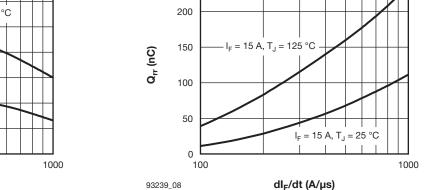


Fig. 9 - Reverse Recovery Waveform and Definitions



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Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

**VS-15EWX06FN-M3** 

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**ORDERING INFORMATION TABLE** 

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Device code	VS-	15	Е	w	x	06	FN	TRL	-M3
							<u> </u>		
		2	3	4	5	6	$\overline{7}$	8	9
	1	Viel		niconduc	atore pr	aduat			
			-		-	Juuci			
				ng (15 =					
	3			iguratior	า:				
	_	E =	Single	diode					
	4	- Pac	kage id	entifier:					
		VV =	D-PAK	C C					
	5	- X =	hyperfa	st recov	very time	Э			
	6	- Vol	tage rati	ng (06 =	= 600 V)				
	7	- FN	= TO-25	52AA					
	8	- • N	one = tu	ıbe					
		• TI	R = tape	e and ree	el				
		• TI	RL = tap	e and re	eel (left	oriented	d)		
		• TI	R = ta	be and r	eel (righ	nt orient	ed)		
	9	- Env	rironmer	ntal digit	:				
		-M3	s = halog	gen-free	, RoHS	-complia	ant, and	l termina	ations le

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-15EWX06FN-M3	75	3000	Antistatic plastic tube							
VS-15EWX06FNTR-M3	2000	2000	13" diameter reel							
VS-15EWX06FNTRL-M3	3000	3000	13" diameter reel							
VS-15EWX06FNTRR-M3	3000	3000	13" diameter reel							

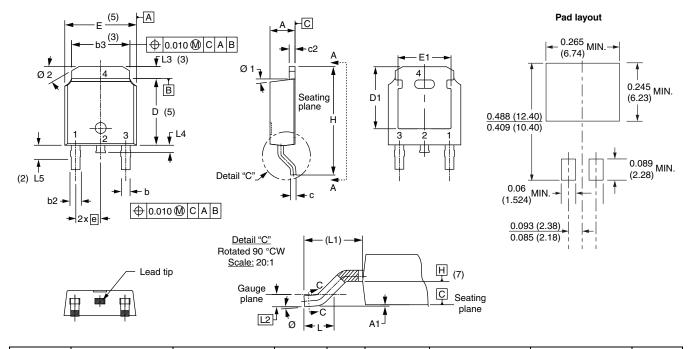
LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95627							
Part marking information	www.vishay.com/doc?95176							
Packaging information	www.vishay.com/doc?95033							
SPICE model	www.vishay.com/doc?96041							





D-PAK (TO-252AA) "M"

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC		
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA

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